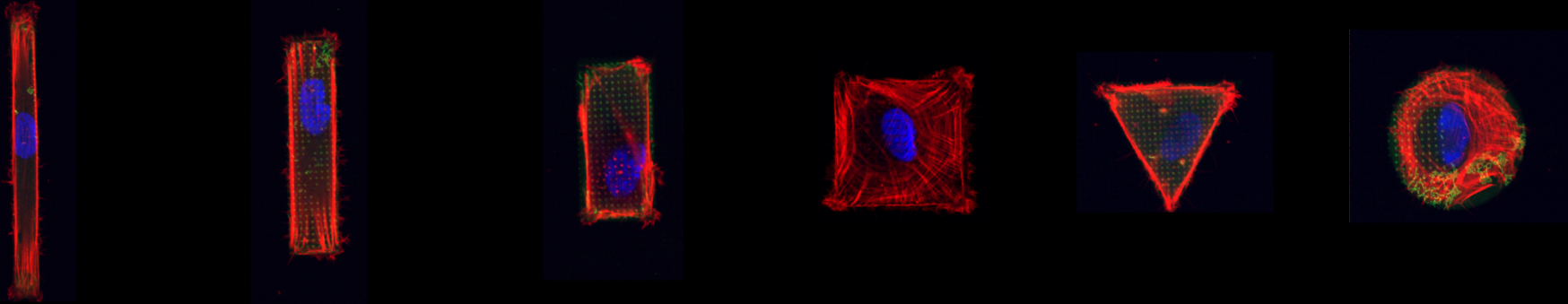


Bioprinting on 3D nanostructures with the Alveole PRIMO

ENGR 241 Fall 2019
Final Presentation

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(Bianxiao Cui's lab, Chemistry)

Mentors: Zeinab Jahed, Xiao Li, Swaroop Kommera & Gaspard Pardon



Motivation & Goals

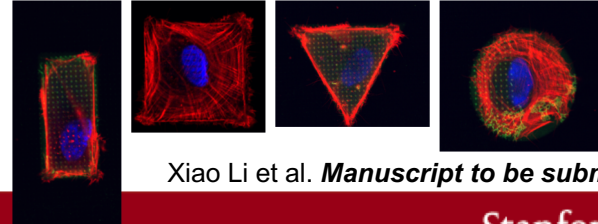
- To fabricate large amounts of vertical nanostructures of various shapes using photolithography & dry etching. *Part A*

This procedure will shrink the nanostructures by dry & wet etching to achieve a resolution down to 200 nm without the need of E-beam lithography. It's less costly and much more efficient.

Xiao Li et al. *Nature Protocols*, vol. 14, p1772–1802 (2019)

- To pattern biomolecules on 3D nanostructures using PRIMO to allow stable cell adhesion in given regions. *Part B*

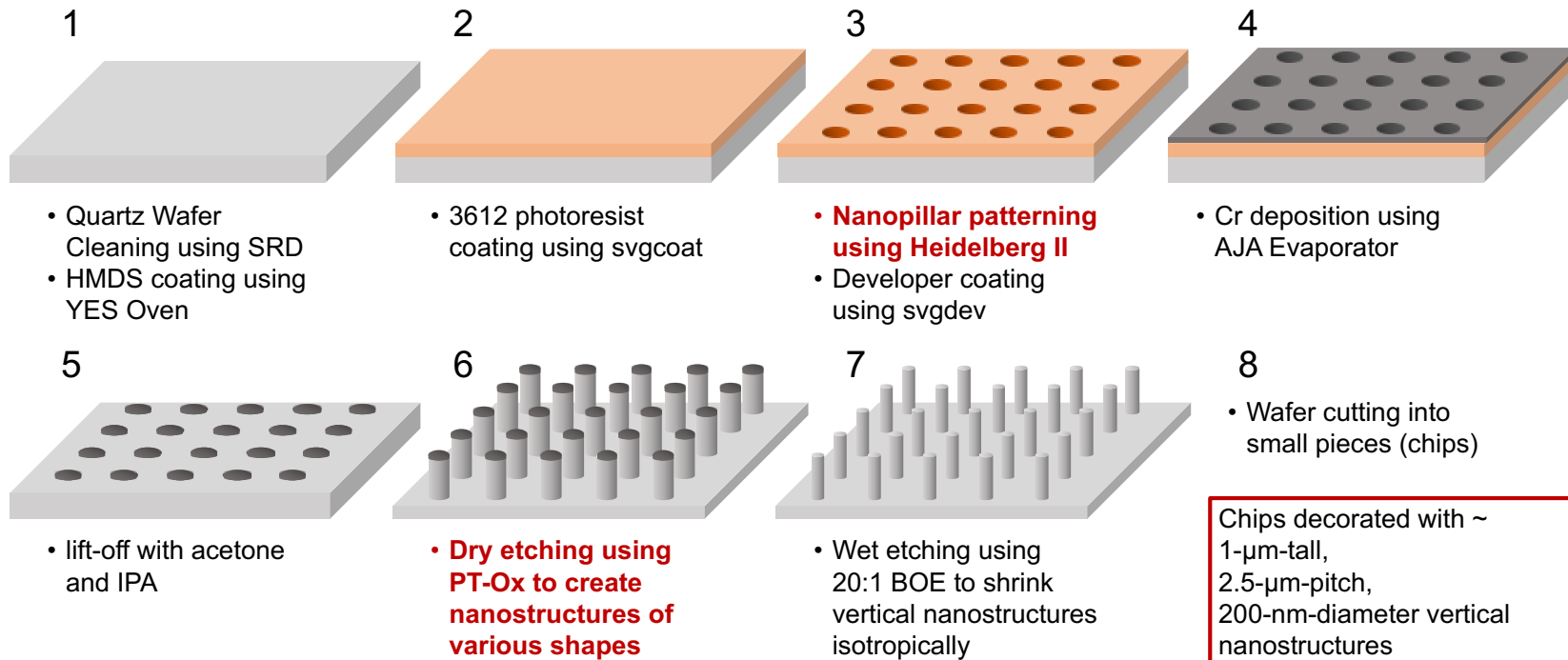
1. Because the surface of nanostructures are not flat, the biomolecules adsorbed on the surface might not be evenly distributed. We will finely tune the Primo Pattern to create a platform for the uniform and stable coating of biomolecules.
2. Control cell adhesion on a defined area, a more systematic way to modulate cell tension, which allows us to study tension-based mechanobiological pathways (YAP, mTOR, Hippo, etc).



Xiao Li et al. *Manuscript to be submitted*

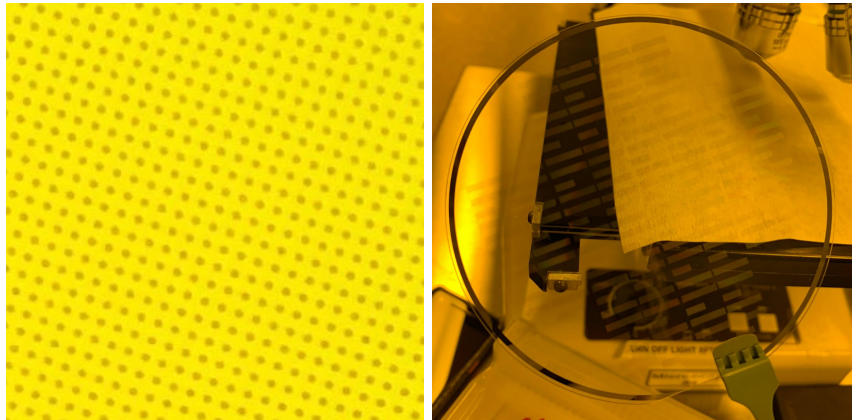
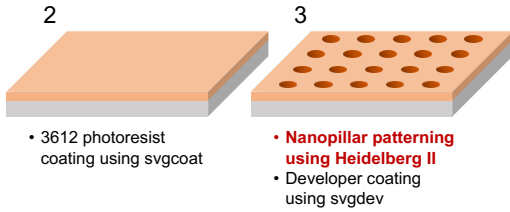
Materials & Methods

Part A - Nanostructured Chip Fabrication



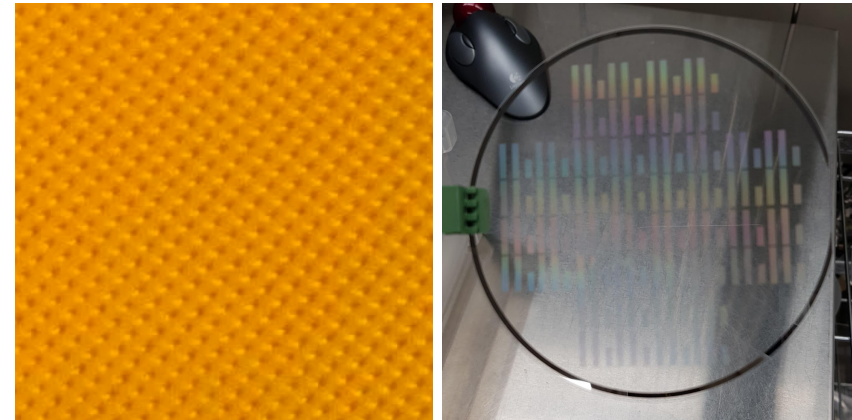
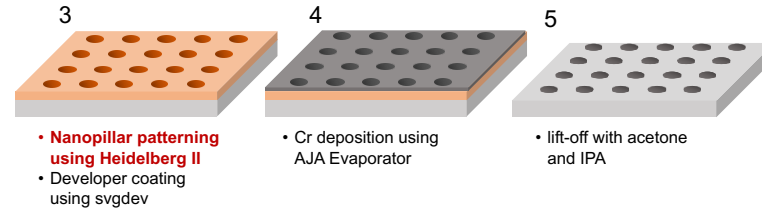
Results (Part A) – Nanostructures Patterning using Heidelberg2

Photolithography Patterning



After Resist Developing; Before Cr deposition
(Featured Pillar diameter ~700 nm)

Cr Deposition and Lift-Off



After Cr deposition and Lift-off
(Featured Pillar diameter ~700 nm)

Results (Part A) –Dry Etching using PT-Ox

Data of Dry Etch Experiments

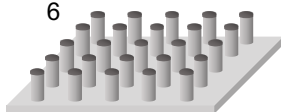
No.	Pattern	CHF ₃ Flow Rate (sccm)	C ₄ F ₈ Flow Rate (sccm)	H ₂ Flow Rate (sccm)	Ar Flow Rate (sccm)	Bias power (W)	Etching Time (min)	Height (nm)	Diameter (nm)	Etching Rate (nm/min)	Slant Angle (deg)	Optimized Parameters
W1	+++++	80	20	40	0	200	3	~1223	~705 (top) ~1031 (bottom)	~408	~82.4	<i>CHF₃ flow rates: 80 sccm</i> <i>ICP Power: 1500 W</i> <i>Pressure: 7 mT</i>
W2	+++++	80	20	40	0	200	3+3	~2150	~613 (top) ~1263 (bottom)	~309	~81.4	
W3	+++++	80	20	40	0	200	3+3+3	~2984	~511 (top) ~1186 (2/3-height) ~1288 (bottom)	~278	~66.6	
W4	+--++	80	0	40	0	200	3	~909	~724 (top) ~967 (bottom)	~303	~82.4	
W5	+--+	80	0	40	0	100	6	~1200	~815 (top) ~1230 (bottom)	~200	~80.2	
W6	+--+	80	0	40	10	50	10	~566	~790 (top) ~1205 (bottom)	~56.6	~69.9	
W7	+----+	80	0	10	0	200	3	~1009	~722 (top) ~1103 (bottom)	~336	~79.3	
W8	+-----	80	0	10	0	100	6	~1293	~775	~216	~90.0	
W9	-++++	0	80	40	20	200	3.3	~1000	~780	~300	~90.0	

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• lift-off with acetone and IPA

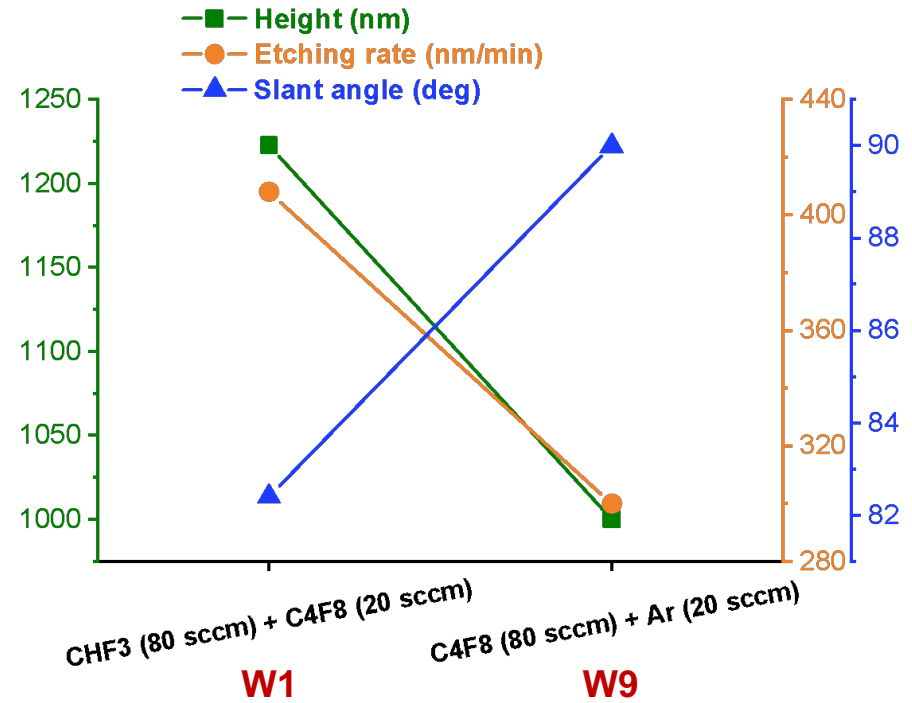
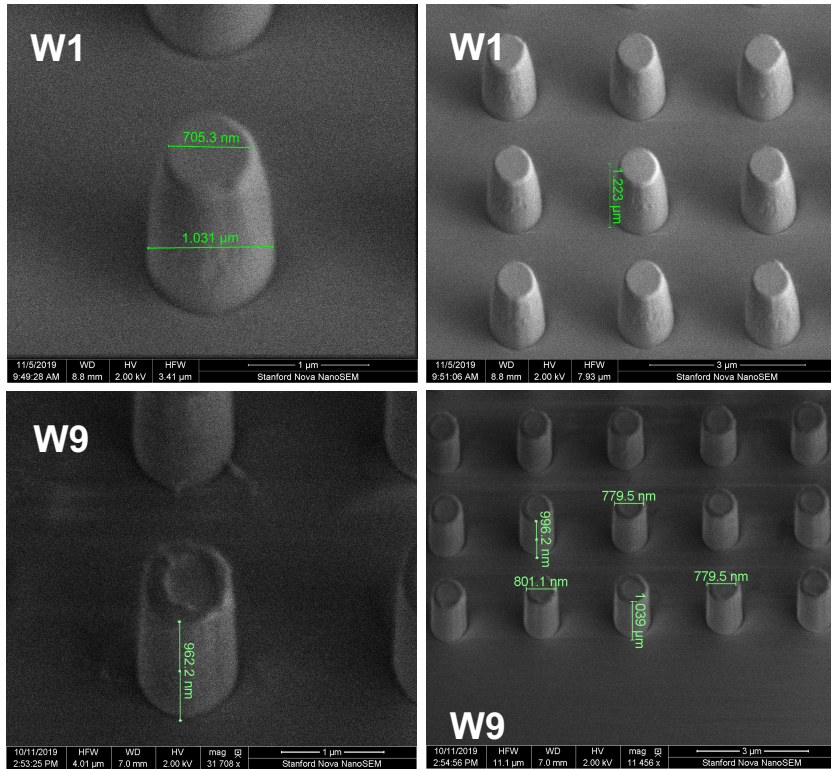
6



• Dry etching using PT-Ox to create nanostructures of various shapes

Results (Part A) – Dry Etching using PT-Ox

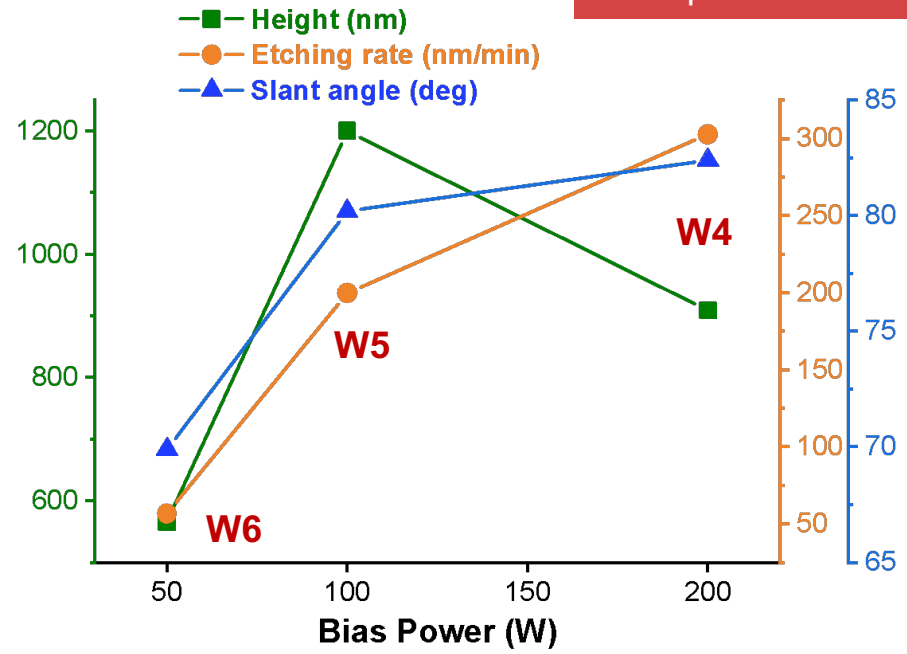
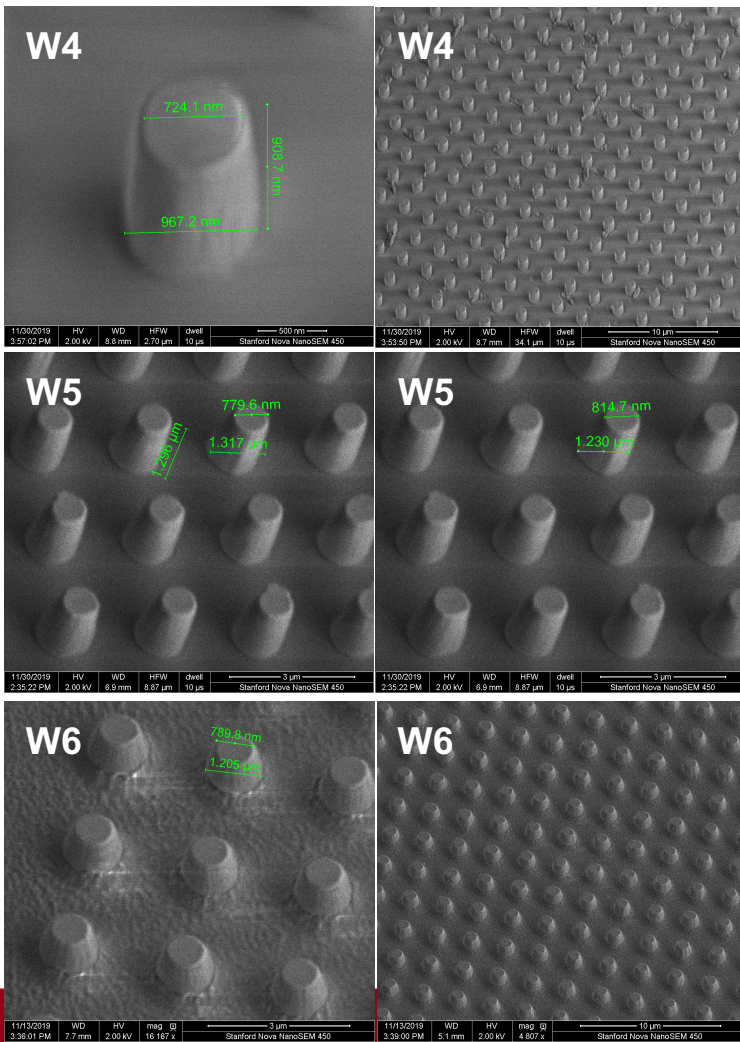
C_xF_y Chemistry effects



Fixed parameters:
H₂ flow rate: 40 sccm; Bias Power: 200 W; Etching time: 3 min

Results (Part A) –Dry Etching using PT-Ox

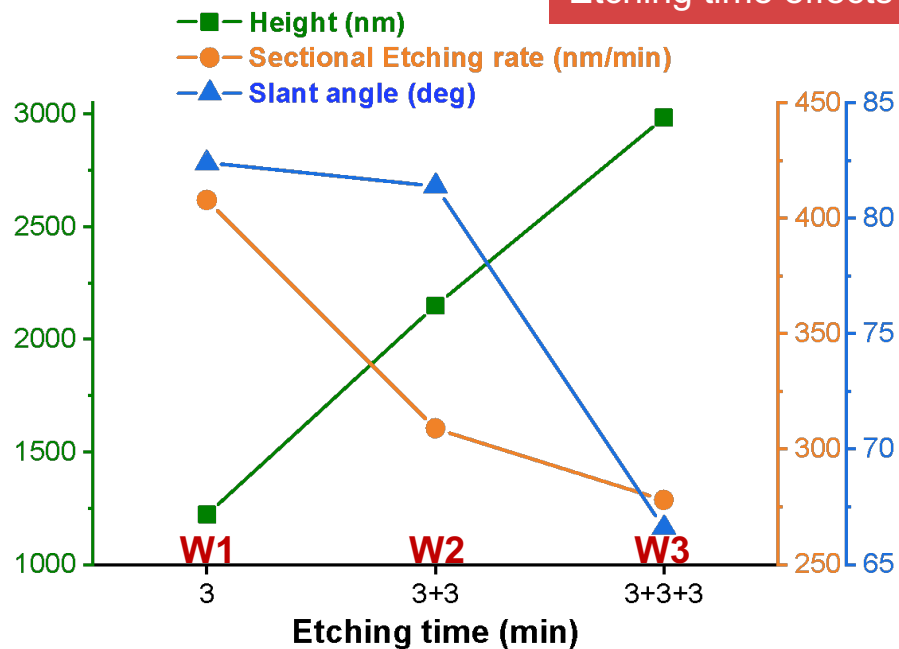
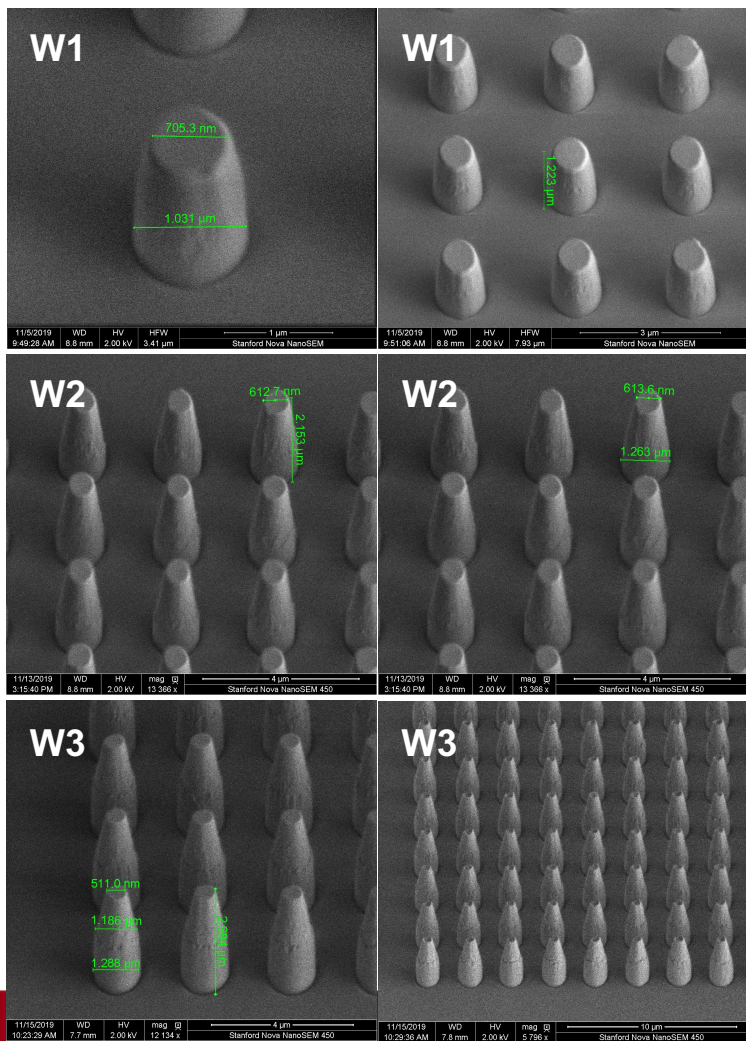
Bias power effects



Fixed parameters:
 CHF_3 flow rate: 80 sccm; H_2 flow rate: 40 sccm; No C_4F_8 & Ar^*

Results (Part A) –Dry Etching using PT-Ox

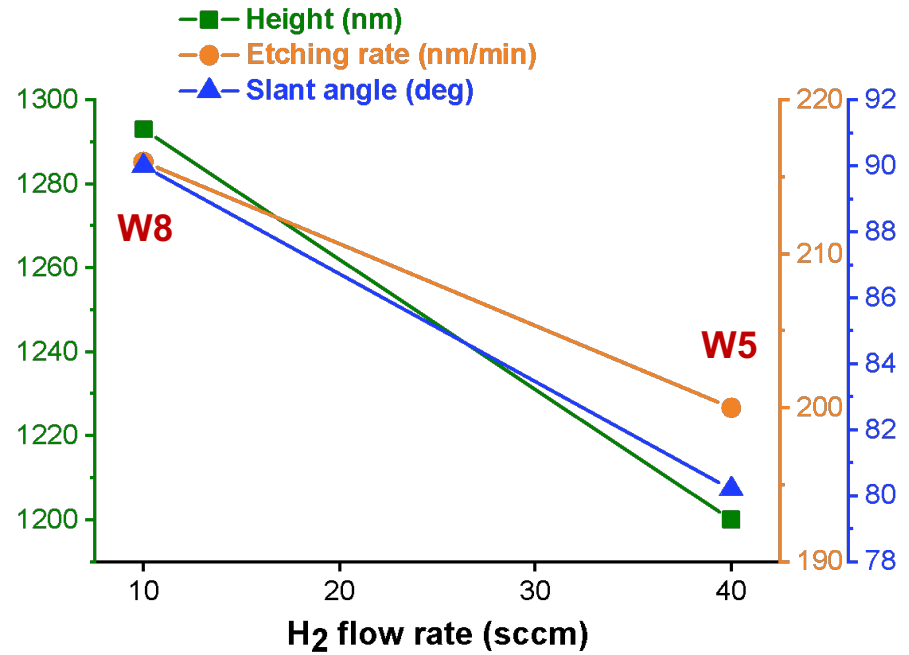
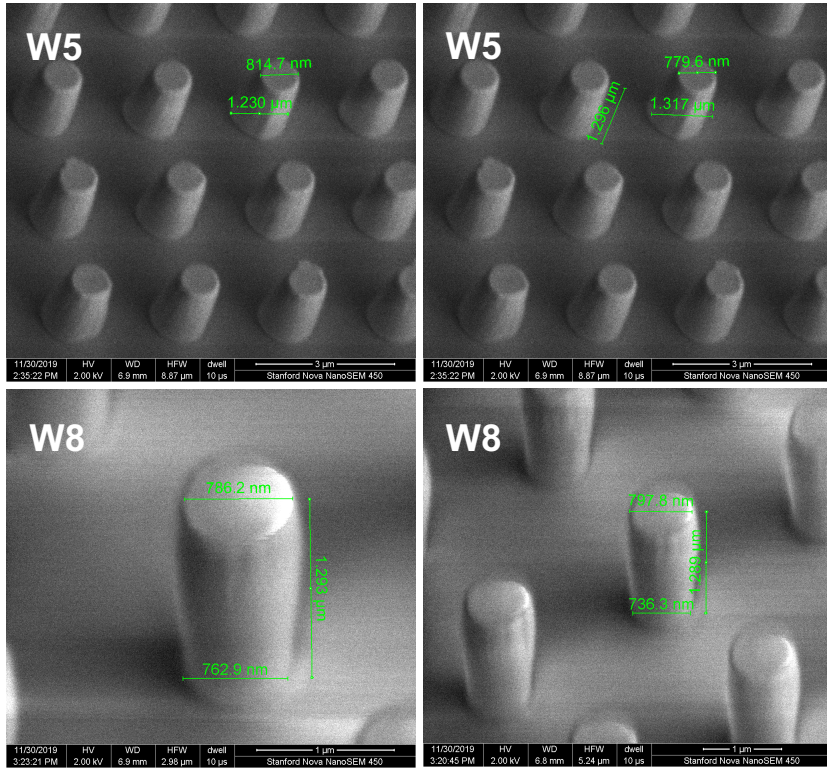
Etching time effects



Fixed parameters:
 CHF_3 flow rate: 80 sccm; C_4F_8 flow rate: 20 sccm;
 H_2 flow rate: 40 sccm; Bias Power: 200 W; No Ar

Results (Part A) – Results – Dry Etching using PT-Ox

H₂ effects



Fixed parameters:
 CHF₃ flow rate: 80 sccm; Bias Power: 100 W;
 Etching time: 6 min; No C₄F₈ & Ar

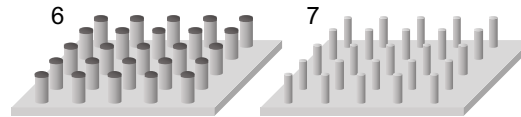
Results (Part A) – Results – Dry Etching using PT-Ox

Brief Summary

- C_4F_8 -based chemistry gives straighter side walls.
- CHF_3 -based chemistry gives tapered side walls (bullet-shaped).
- High H_2 level leads to slower etching rates and the formation of more tapered side walls.
- High Bias power results in faster etching rates and the creation of straighter nanopillars.

Results (Part A) – Wet Etching

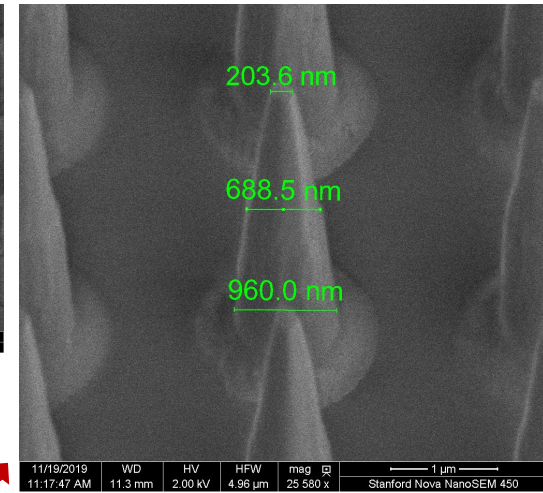
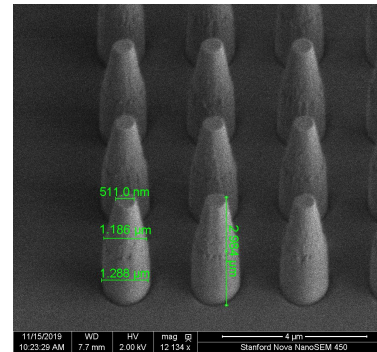
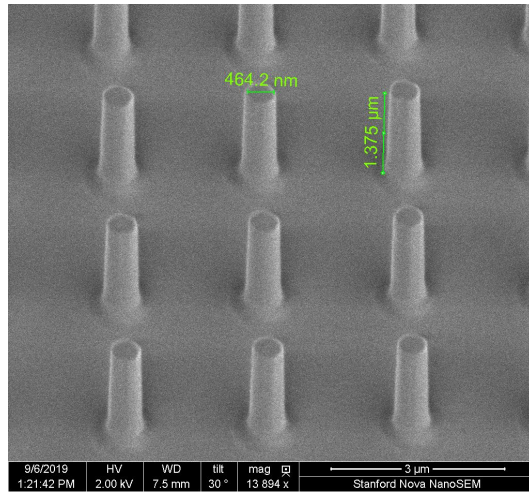
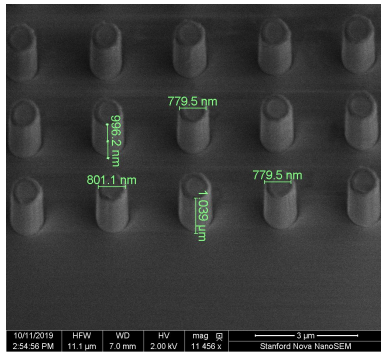
Isotropic Shrinkage of the Pillars by Wet Etching



• Dry etching using PT-Ox to create nanostructures of various shapes

• Wet etching using 20:1 BOE to shrink vertical nanostructures isotropically

Wet etching can also give us some interesting shapes



- 1) Cr Etching for 20 min
- 2) 20:1 BOE for 5 min

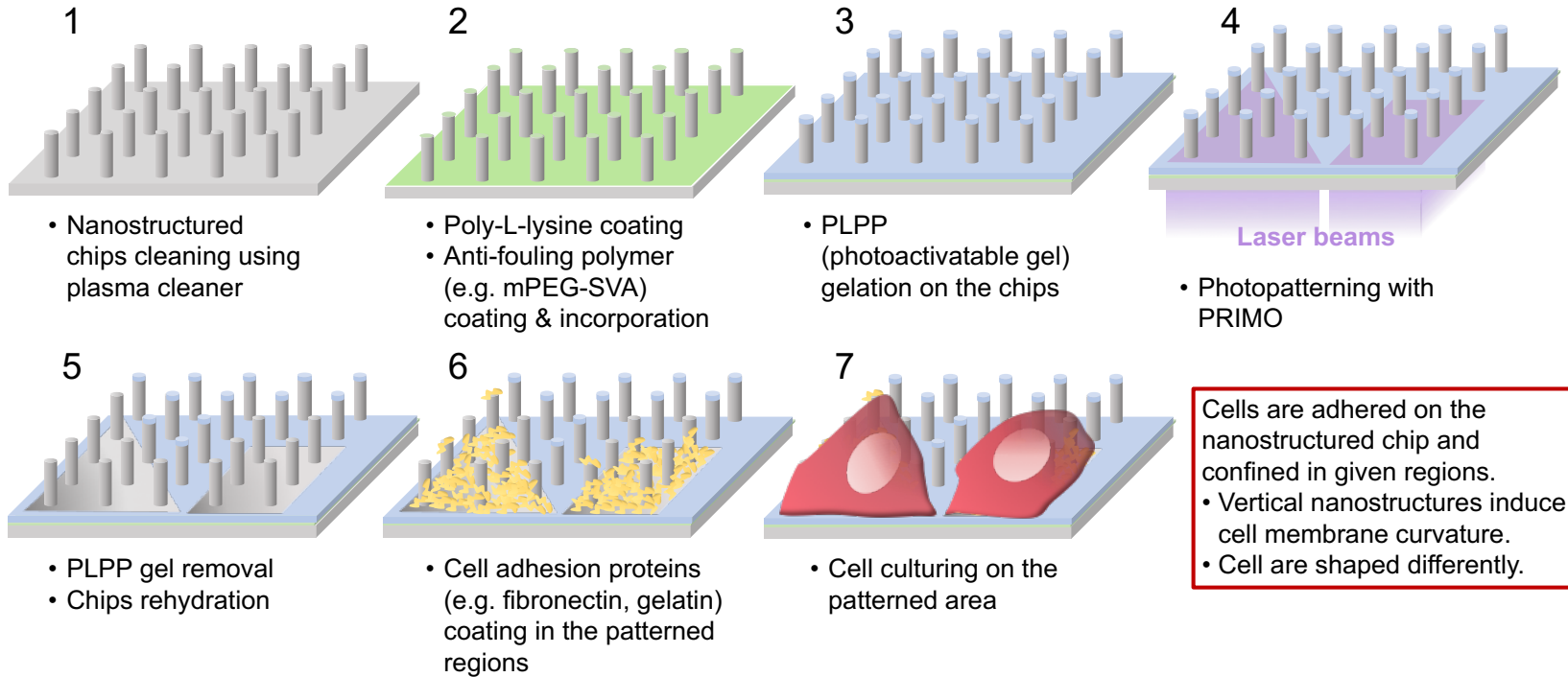
- Height: raised by ~330 nm
- Diameter: shrunk by ~320 nm

- 1) No Cr Etching
- 2) 20:1 BOE for 4 min

- Top Diameter: shrunk by ~307 nm
- Middle Diameter: shrunk by ~498 nm
- Bottom Diameter: shrunk by ~320 nm

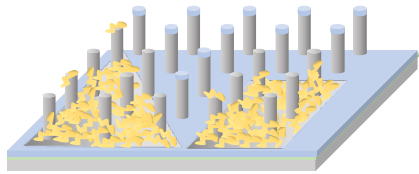
Materials & Methods

Part B - Bioprinting using PRIMO

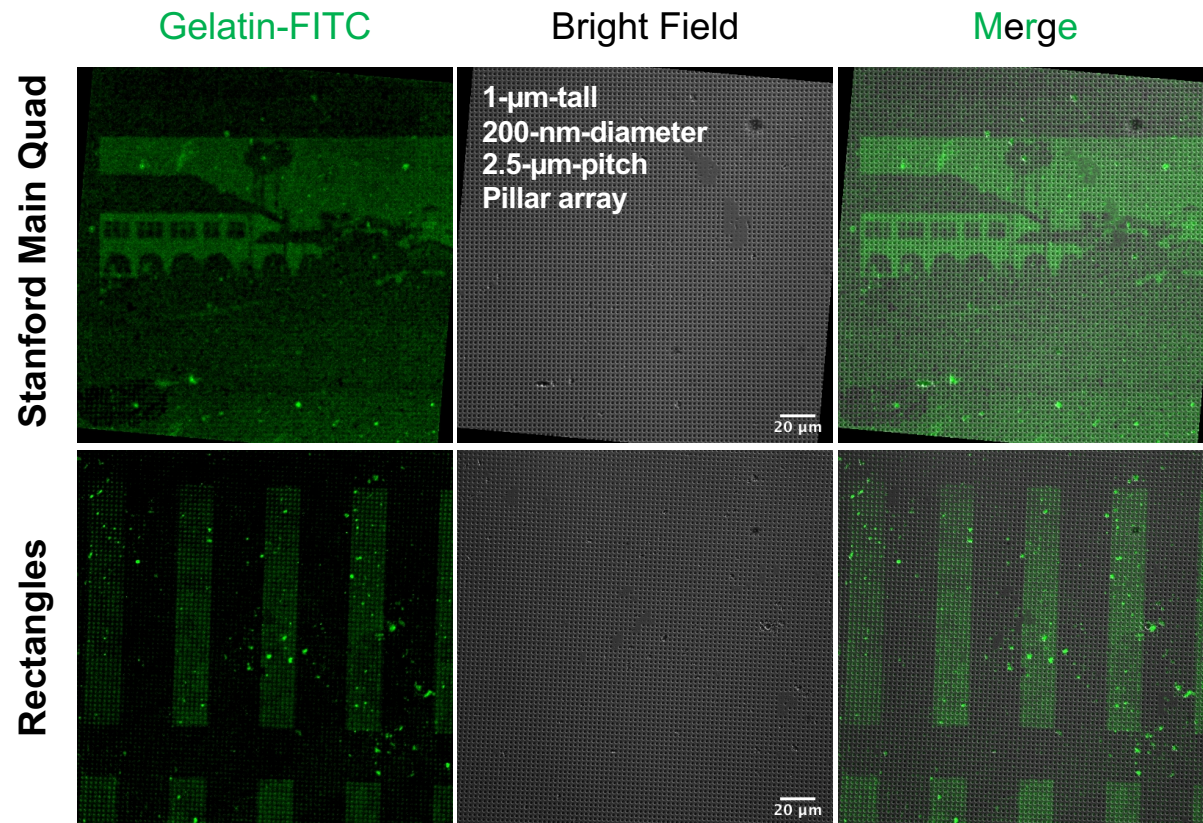


Results (Part B) – Bioprinting using PRIMO

PRIMO Patterning

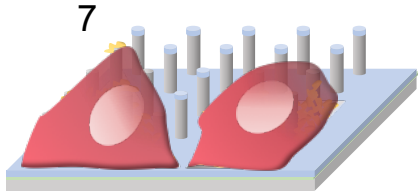


- Nanopillar chips are coated with **F**luorescein **I**so**T**hio**C**yanate-tagged gelatin.
- Images are resolved using confocal microscope (60X).



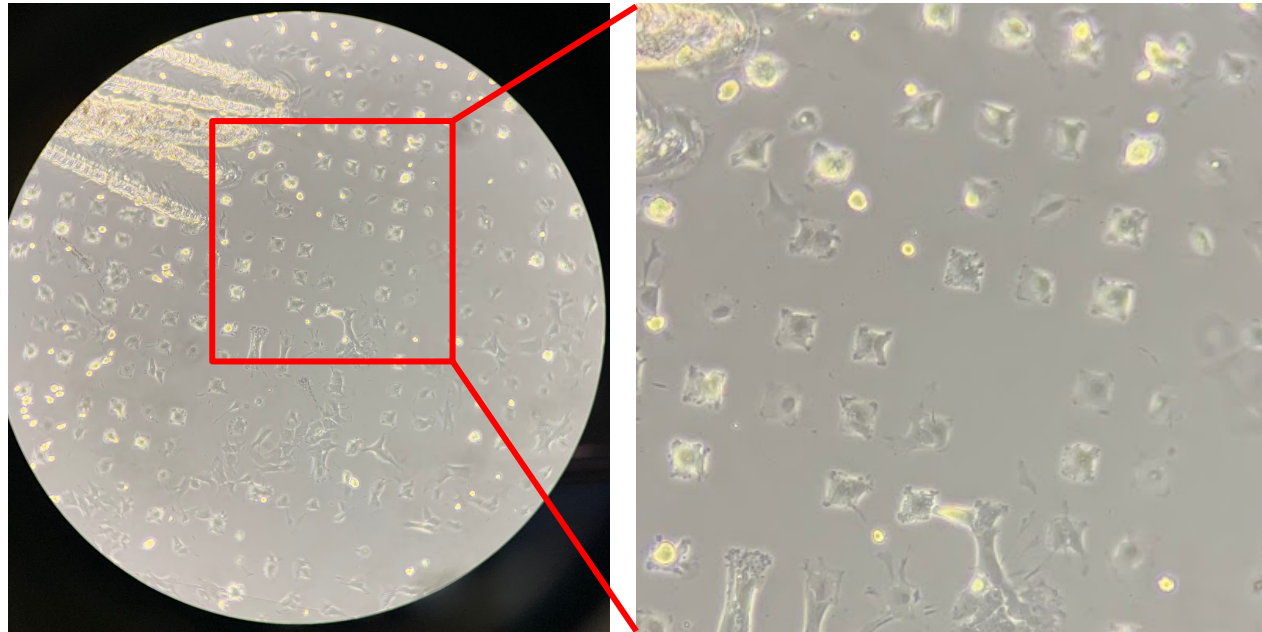
Results (Part B) – Bioprinting using PRIMO

Mammalian Cells Culture on PRIMO-patterned Nanopillar Chip



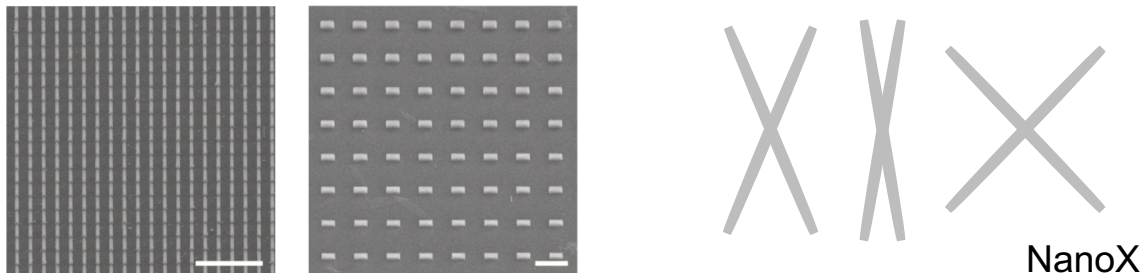
- Cell culturing on the patterned area

- Nanopillar chips are patterned with **square** array.
- Nanopillar chips are then coated with unlabeled gelatin.
- Cells are adhered on patterned/gelatin-coated area.
- Images are resolved using bright field mode in epifluorescence microscope.



Future Plans (Winter Quarter)

- Apart from nanopillar-derived patterns, we are also going to fabricate chips decorated with **nanobar (various sizes)**, **nanoX (various angles)** to study how cells respond to various physical perturbations and investigate cell membrane curvature-dependent biological pathways.

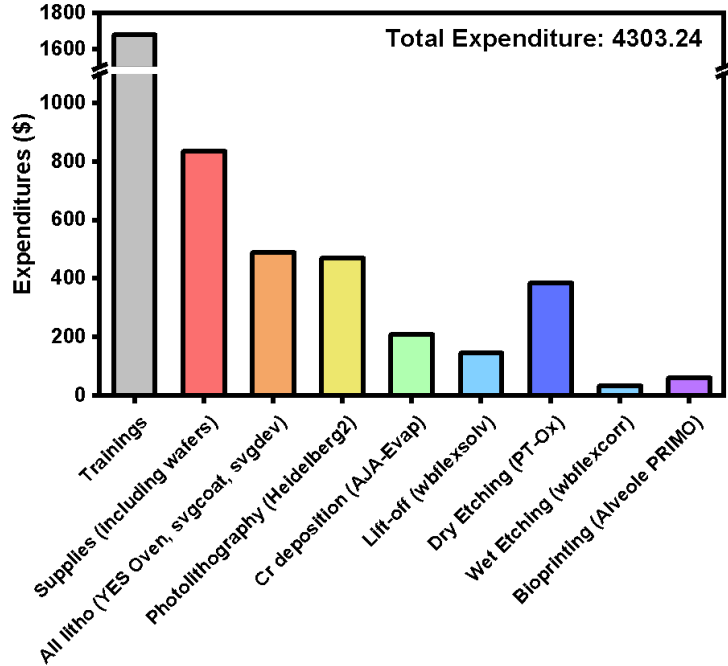


Zhao et al., 2017, *Nat. Nanotechnol.* 12
Li et al., 2019, *Nat. Protoc.* 14

- Aside from using 4' quartz wafer, we plan to fabricate vertical nanostructures and print biomolecules on **thinner chips**, which can be used for **super-resolution cell imaging** experiments.
- Design PRIMO patterns and Optimize PRIMO experimental conditions, such as PLL-mPEG coating density, PLPP gelation protocol, and UV dose, etc.

Quarterly Budget

Acknowledgements



- Mentors and SNF staffs for useful advice. Special thanks to **Zeinab, Xiao, Swaroop, Usha, Gaspard** for their insights & assistances on nanofabrication, characterization and PRIMO.
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- Stanford Nano Shared Facilities (SNSF)
- Stanford University Department of Chemistry
- Prof. Jonathan Fan
- Prof. Roger T. Howe
- Charmaine Chia (Course TA)

